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IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re the Application of

Applicant Kaiping Liu

Docket Number: TI-34717.1

Serial No.: 10/785,623

Art Unit: 2812

Filed: 02/24/04

Examiner: TBD

For: method to Produce Localized Halo for MOS Transistor

CERTIFICATION OF FACSIMILE TRANSMISSION

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FACSIMILE COVER SHEET

<input checked="" type="checkbox"/> FACSIMILE COVER SHEET	<input checked="" type="checkbox"/> AMENDMENT <u>Preliminary - resubmitted (5</u>
<input type="checkbox"/> NEW APPLICATION	<u>pages)</u>
<input type="checkbox"/> DECLARATION	<input type="checkbox"/> EOT
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<input type="checkbox"/> DIVISIONAL APP'N	<input type="checkbox"/> ELECTION
NAME OF INVENTOR(S): Kaiping Liu	
TITLE OF INVENTION: Method to Produce Localized Halo for MOS Transistor	
TI FILE NO.: TI-34717.1	DEPOSIT ACCT. NO.: 20-0668
FAXED: 4-6-05 DUE: 4-24-05 ATTY/SEC'Y: RAK/kjv	
RECEIPT DATE & SERIAL NO.: Serial No.: 10/785,623 Filing Date: 02/24/04	

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Karen Vertz
Karen Vertz

4-6-05
Date

Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

PRELIMINARY AMENDMENT

Dear Sir:

Prior to the examination of the above-identified application, please amend
as follows:

TI-34717.1 Page 1 of 5